

ESD237-B1-W0201

Bi-directional ESD protection device, 8 V, 7 pF, 0201

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Product description

This Infineon ESD (electrostatic discharge) protection device has a bi-directional and symmetric I/V characteristic and excellent clamping performance.

Feature list

- ESD / transient protection according to:
 - IEC61000-4-2 (ESD): ± 16 kV (air) / ± 16 kV (contact)
 - IEC61000-4-4 (EFT): ± 2 kV / ± 40 A (5/50 ns)
 - IEC61000-4-5 (Surge): ± 3 A (8/20 μ s)
- Bi-directional maximum working voltage: $V_{WM} = \pm 8$ V
- Line capacitance: $C_L = 7$ pF at $f = 1$ MHz
- Clamping voltage: $V_{cl} = 13$ V at $I_{TLP} = 16$ A with $R_{dyn} = 0.21 \Omega$
- Very low leakage current: $I_L = 1$ nA
- Small form factor SMD size 0201, low profile (0.58 x 0.28 x 0.15 mm³)



Potential applications

- Keypads, touchpads, buttons, convenience keys, LCD displays, cameras, audio lines
- Mobile communication, notebooks, tablets, desktop computers, modules (WIFI, fingerprint, flash)

Product validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

Device information

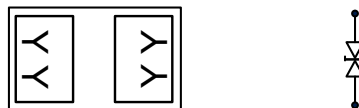


Figure 1 Pin configuration with marking (bottom view)

Table 1 Part information

| Product name / Ordering code | Package | Pin configuration | Marking | Pieces / Reel |
|---|---------|------------------------|---------|---------------|
| ESD237-B1-W0201/ESD237B1W0201E6327XTSA1 | WLL-2-1 | 1 line, bi-directional | YY | 15 k |

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1 Absolute maximum ratings

1 Absolute maximum ratings

Table 2 Absolute maximum ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Values | | Unit | Note or test condition |
|-----------------------|---------------------|--------|------|------------------|---|
| | | Min. | Max. | | |
| Working voltage | V_{WM} | -8 | +8 | V | |
| ESD discharge voltage | V_{ESD} (contact) | -16 | +16 | kV | Discharge network: $R = 330 \Omega$, $C = 150 \text{ pF}$ ¹⁾ |
| | V_{ESD} (air) | -16 | +16 | | |
| Peak pulse power | P_{PK} | - | 42 | W | Stress pulse: 8/20 μs current waveform ²⁾ |
| Peak pulse current | I_{PP} | -3 | +3 | A | |
| Operating temperature | T_{op} | -55 | +85 | $^\circ\text{C}$ | |
| Storage temperature | T_{stg} | -55 | +150 | | |

Attention: *Stresses above the maximum values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings. Exceeding only one of these values may cause irreversible damage to the component.*

¹ Based on IEC61000-4-2.

² Based on IEC61000-4-5.

2 Electrical characteristics

2 Electrical characteristics

Note: $T_A = 25^\circ\text{C}$, unless otherwise specified. Device is electrically symmetrical.

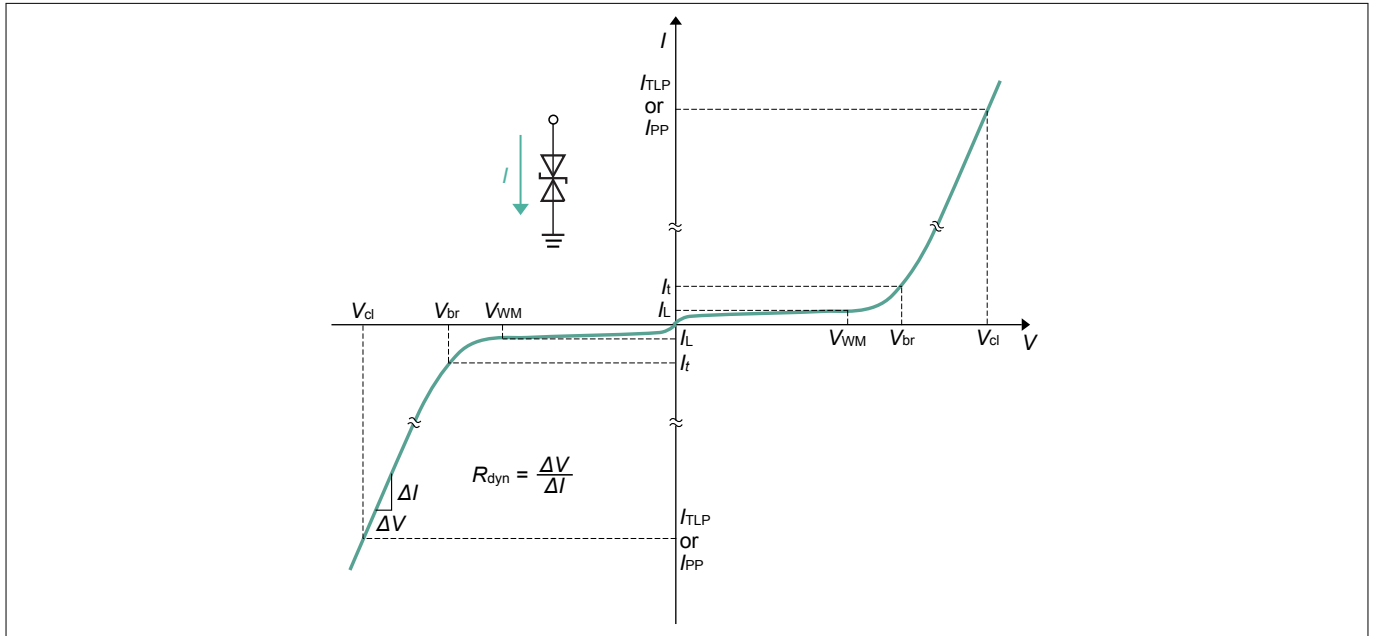


Figure 2 ***I/V* characteristic curve**

Table 3 ***I/V* characteristic parameters**

| Symbol | Parameter |
|-----------|---|
| I_L | Leakage current |
| I_{PP} | Peak pulse current, based on IEC61000-4-5 |
| I_t | Test current |
| I_{TLP} | TLP current |
| R_{dyn} | Dynamic resistance |
| V_{br} | Breakdown voltage |
| V_{cl} | Clamping voltage |
| V_t | Test voltage |
| V_{WM} | Maximum working voltage |

2 Electrical characteristics

Table 4 DC characteristics

| Parameter | Symbol | Values | | | Unit | Note or test condition |
|-------------------|----------|--------|------|------|------|------------------------|
| | | Min. | Typ. | Max. | | |
| Breakdown voltage | V_{br} | 9 | 10.5 | 12 | V | $I_t = 1 \text{ mA}$ |
| Leakage current | I_L | – | 1 | 100 | nA | $V_{WM} = 8 \text{ V}$ |

Table 5 AC characteristics

| Parameter | Symbol | Values | | | Unit | Note or test condition |
|-------------------|--------|--------|------|------|------|--------------------------------------|
| | | Min. | Typ. | Max. | | |
| Line capacitance | C_L | – | 7 | – | pF | $V = 0 \text{ V}, f = 1 \text{ MHz}$ |
| | | – | 7 | – | | $V = 0 \text{ V}, f = 1 \text{ GHz}$ |
| Series inductance | L_S | – | <1 | – | nH | Extracted from S-parameters |

Table 6 Protection characteristics

| Parameter | Symbol | Values | | | Unit | Note or test condition |
|--|-----------|--------|------|------|----------|--------------------------|
| | | Min. | Typ. | Max. | | |
| Clamping voltage (TLP) ^{3) 4)} | V_{cl} | – | 11.5 | – | V | $I_{TLP} = 4 \text{ A}$ |
| | | – | 12.3 | – | | $I_{TLP} = 8 \text{ A}$ |
| | | – | 14 | – | | $I_{TLP} = 16 \text{ A}$ |
| | | – | 17 | – | | $I_{TLP} = 30 \text{ A}$ |
| Clamping voltage (8/20 μs) ⁵⁾ | | – | 10 | – | | $I_{PP} = 1 \text{ A}$ |
| | | – | 12 | – | | $I_{PP} = 3 \text{ A}$ |
| Dynamic resistance ³⁾ | R_{dyn} | – | 0.21 | – | Ω | |

³⁾ TLP parameters: $Z_0 = 50 \Omega$, $t_p = 100 \text{ ns}$, $t_r = 0.6 \text{ ns}$, averaging window 30-60 ns.

⁴⁾ Refer to application note AN210 [2]

⁵⁾ $t_p = 8/20 \mu\text{s}$. Stress pulse based on IEC61000-4-5.

3 Typical characteristic diagrams

3 Typical characteristic diagrams

Note: $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified.

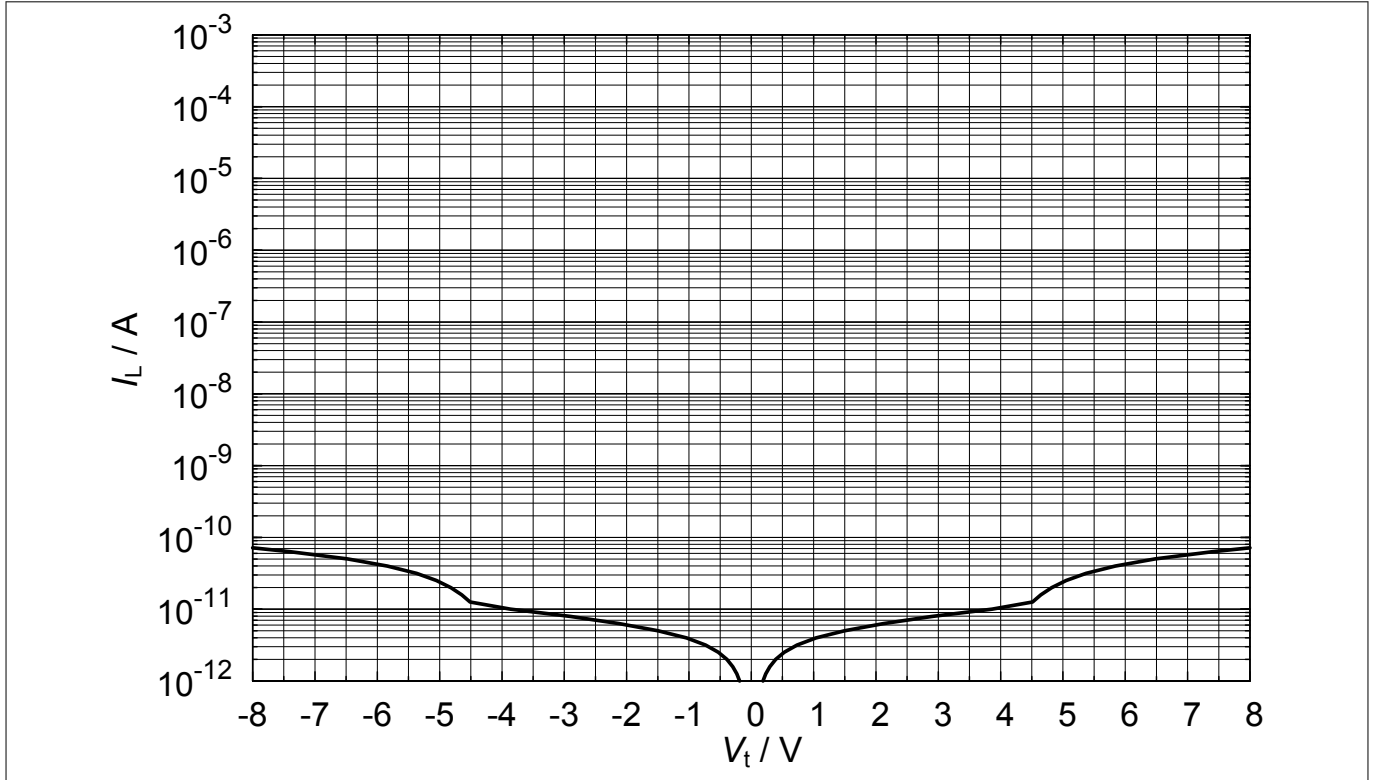


Figure 3 Leakage current: $I_L = f(V_t)$

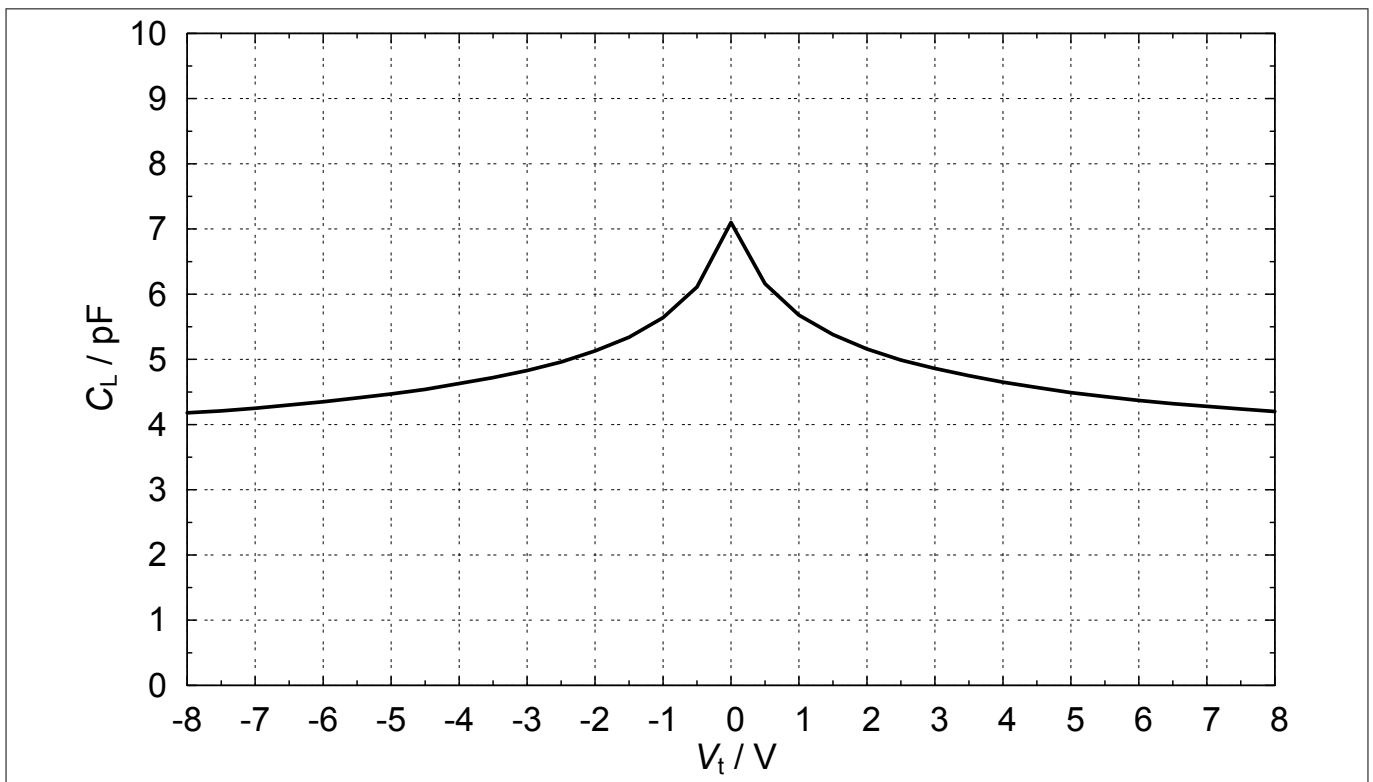


Figure 4 Line capacitance: $C_L = f(V_t)$, $f = 1\text{ MHz}$

3 Typical characteristic diagrams

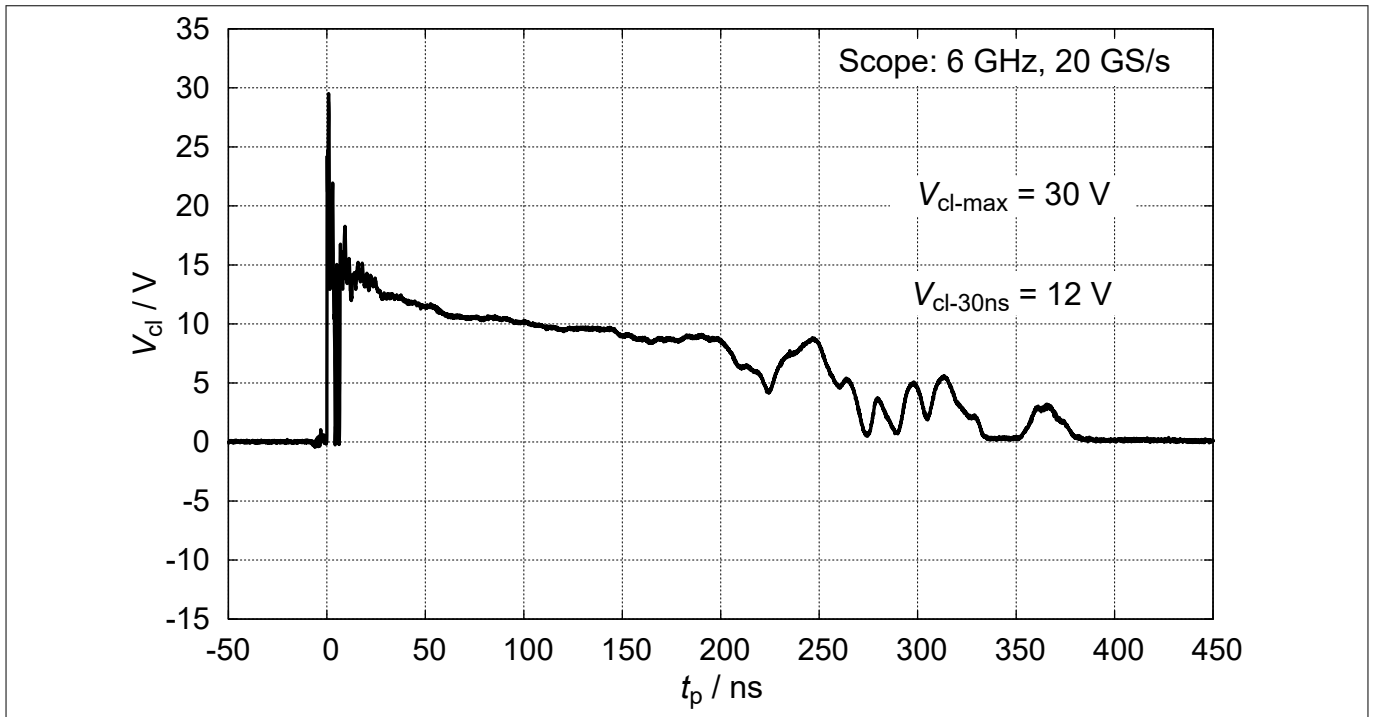


Figure 5 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 8 kV positive pulse based on IEC61000-4-2

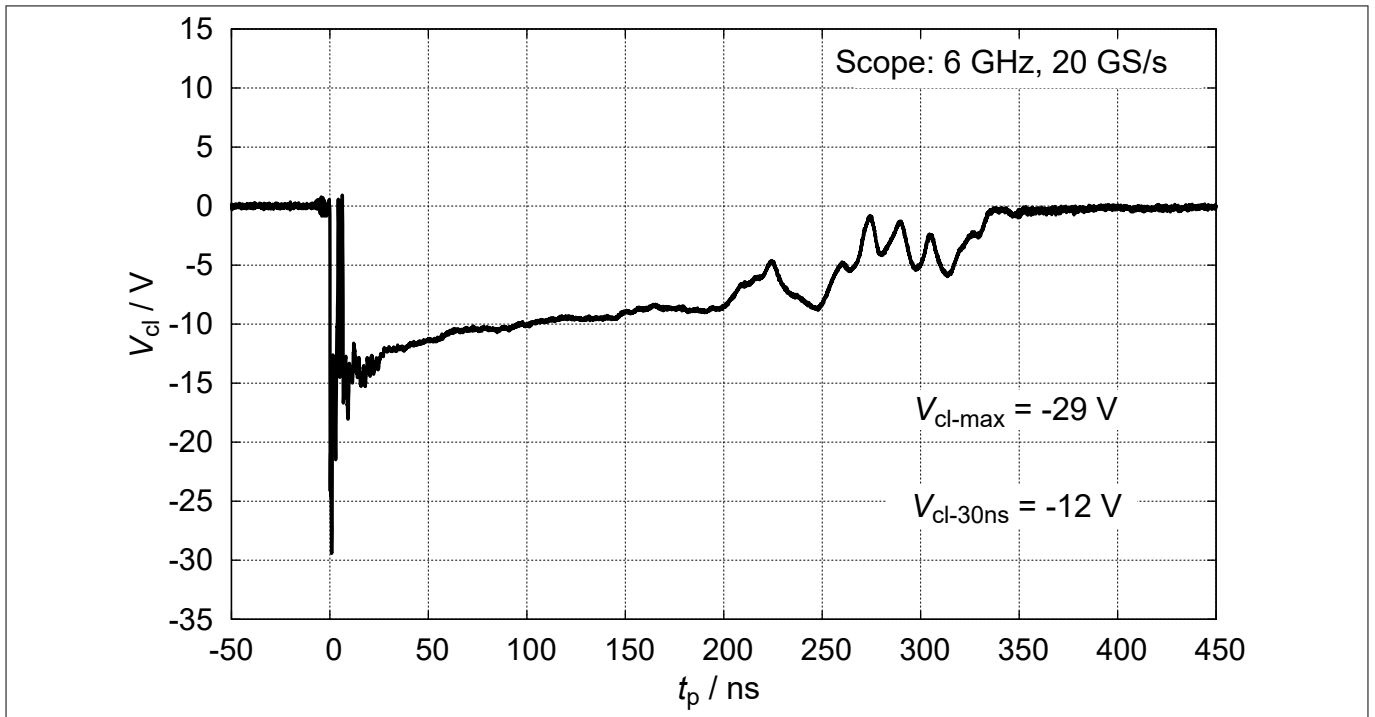


Figure 6 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 8 kV negative pulse based on IEC61000-4-2

3 Typical characteristic diagrams

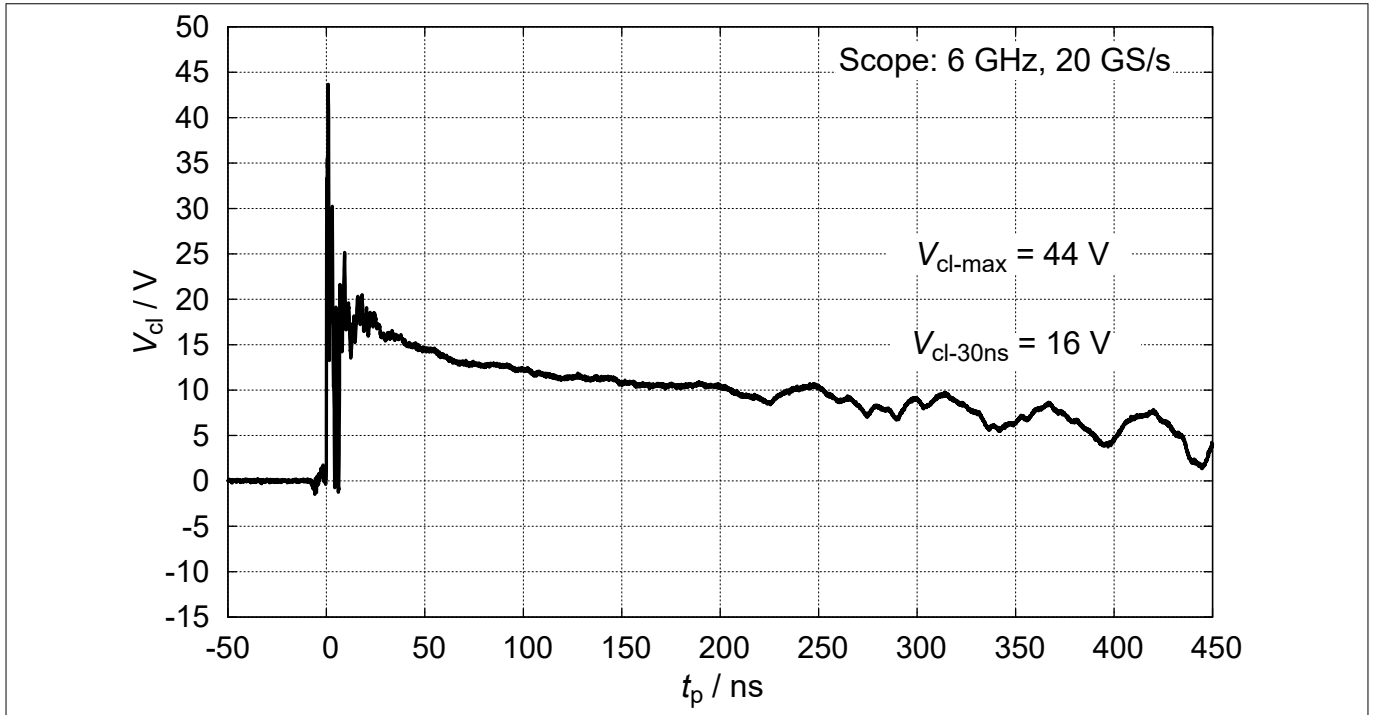


Figure 7 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 15 kV positive pulse based on IEC61000-4-2

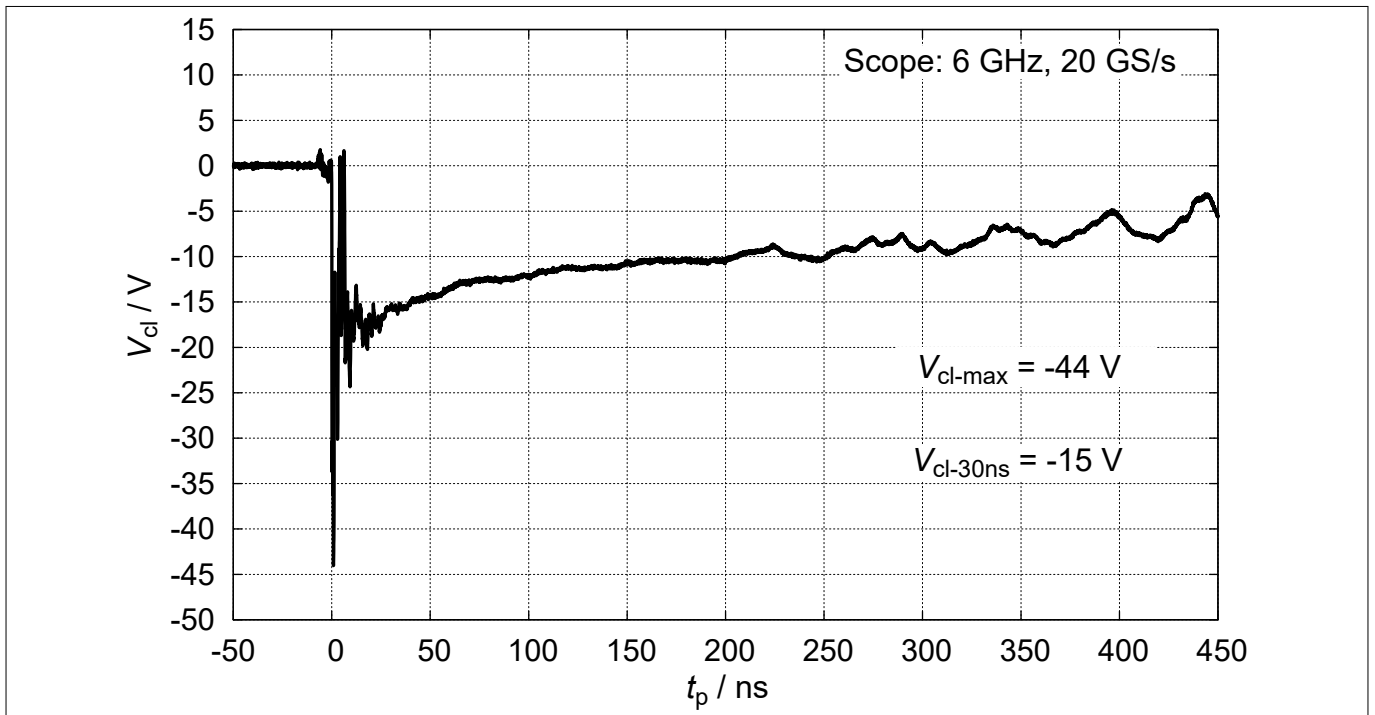


Figure 8 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 15 kV negative pulse based on IEC61000-4-2

3 Typical characteristic diagrams

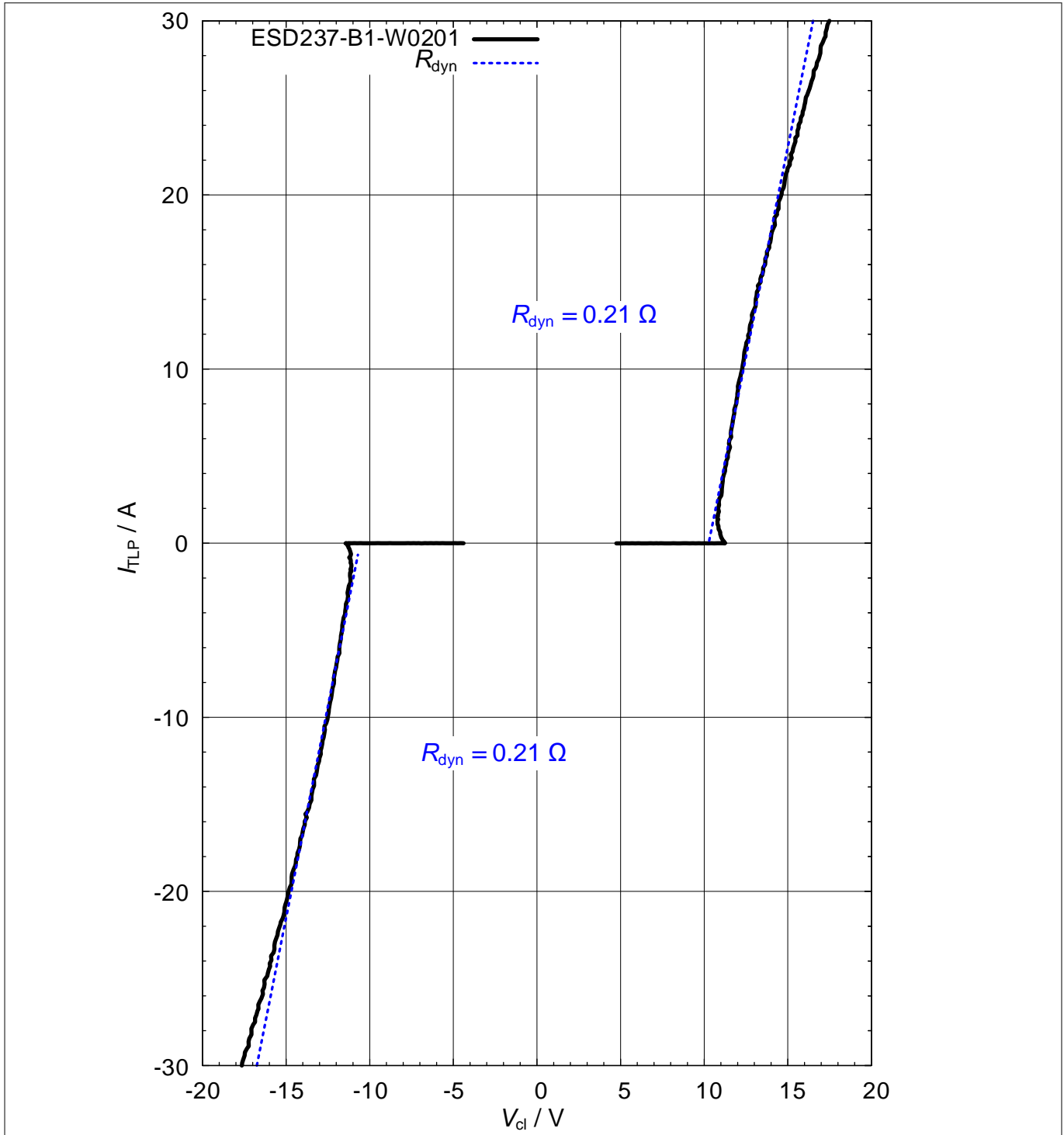


Figure 9 Clamping voltage (TLP): $I_{TLP} = f(V_{cl})$

3 Typical characteristic diagrams

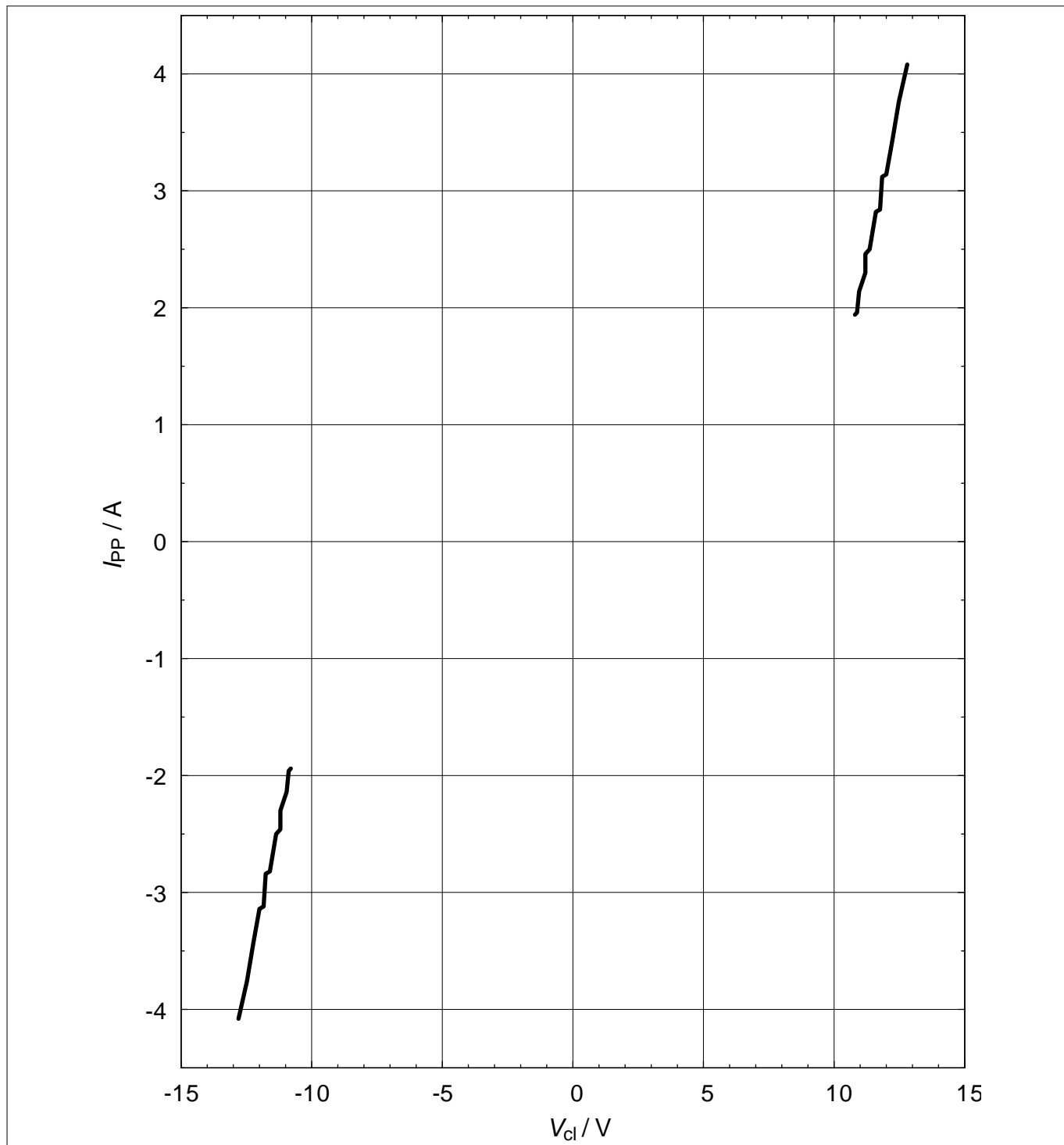


Figure 10 Clamping voltage (Surge): $I_{PP} = f(V_{cl})$, based on IEC61000-4-5

3 Typical characteristic diagrams

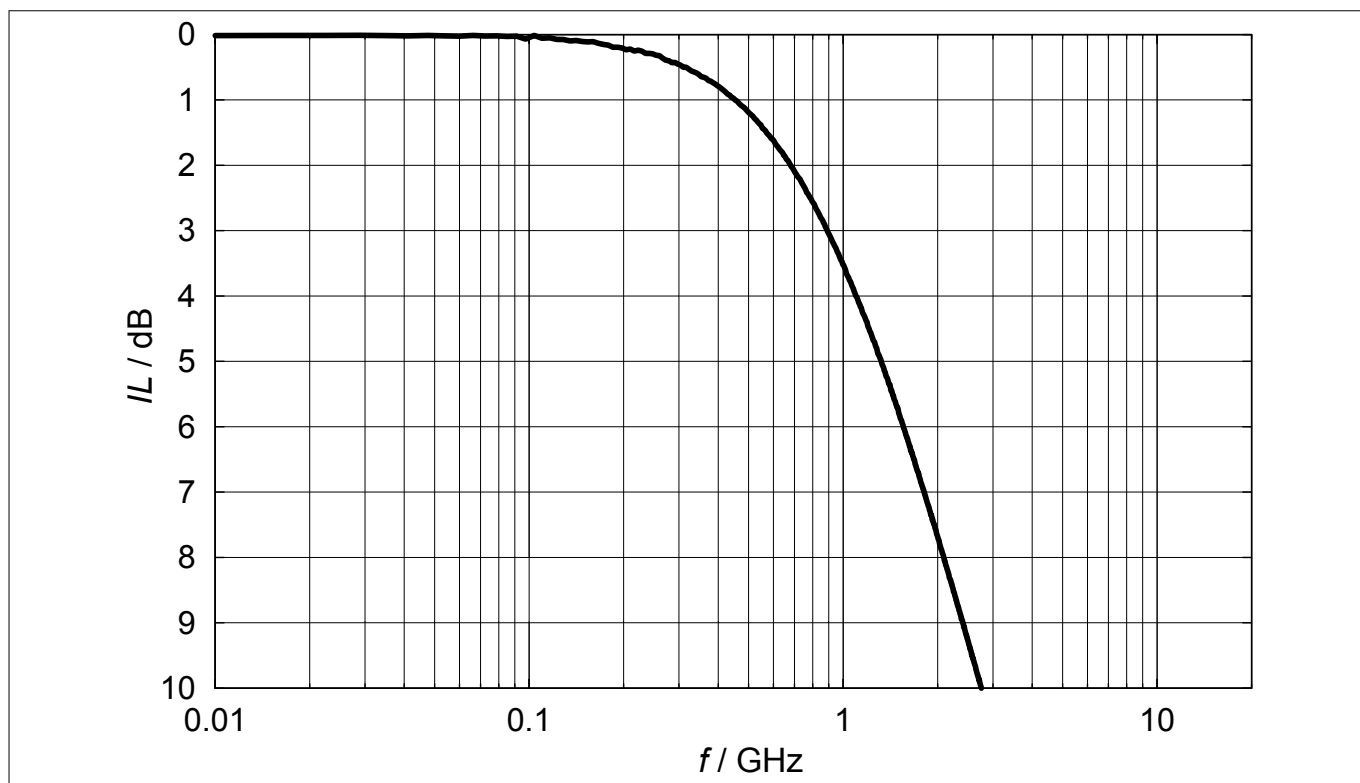


Figure 11 Insertion loss: $IL = f(f)$, measured in a 50 Ω system

4 Package information WLL-2-1

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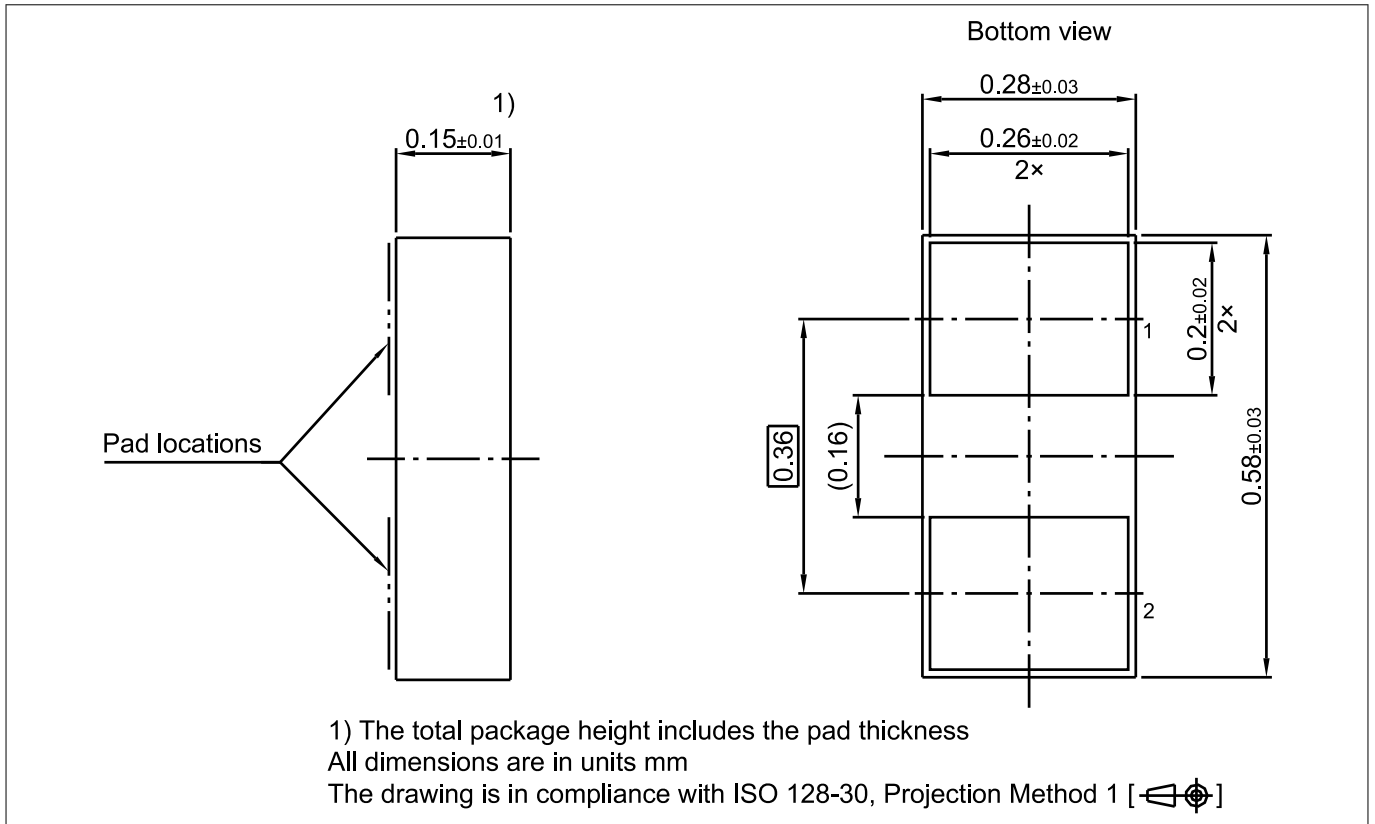


Figure 12 WLL-2-1 package

Note: For package information including footprint, packing and assembly recommendation refer to:

<https://www.infineon.com/packages/SG-WLL-2-1/>

5 References

5 References

| | |
|-----|---|
| [1] | Infineon AG - Understanding ESD protection device characteristics |
| [2] | Infineon AG - Application note AN210 : Effective ESD Protection Design at System Level Using VF-TLP Characterization Methodology |

6 Revision history

| Document version | Date of release | Description of changes |
|-------------------------|------------------------|--|
| 1.0 | 2016-10-18 | <ul style="list-style-type: none">• First final release of datasheet |
| 2.0 | 2021-04-15 | <ul style="list-style-type: none">• New datasheet layout• V_{cl} (TLP) values at 4 A, 8 A added• Potential applications updated |

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